

MITSUBISHI THYRISTOR MODULES  
**TM130RZ/EZ/GZ-M,-H**

HIGH POWER GENERAL USE  
 INSULATED TYPE

**TM130RZ/EZ/GZ-M,-H**



(RZ Type)

- **IT (AV)** Average on-state current ..... **130A**
- **IF (AV)** Average forward current ..... **130A**
- **VRRM** Repetitive peak reverse voltage ..... **400/800V**
- **VDRM** Repetitive peak off-state voltage ..... **400/800V**
- **MIX DOUBLE ARMS**
- **Insulated Type**
- **UL Recognized**

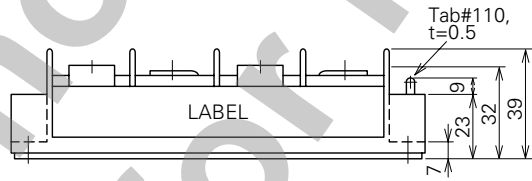
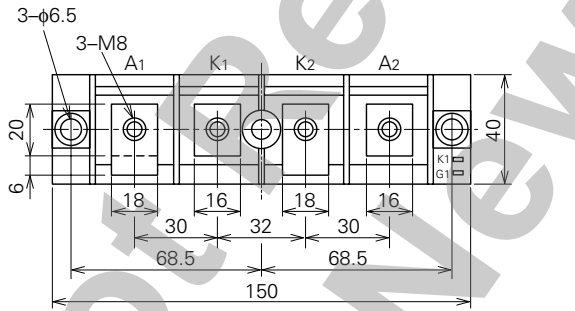
Yellow Card No. E80276 (N)  
 File No. E80271

**APPLICATION**

DC motor control, NC equipment, AC motor control, contactless switches, electric furnace temperature control, light dimmers

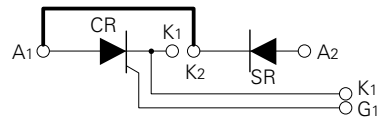
**OUTLINE DRAWING & CIRCUIT DIAGRAM**

Dimensions in mm

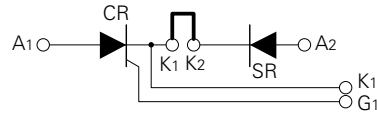


(RZ Type)

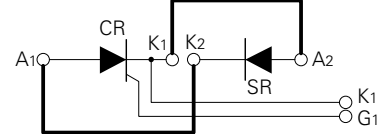
(RZ)



(EZ)



(GZ)



(Bold line is connective bar.)

## TM130RZ/EZ/GZ-M,-H

MEDIUM POWER GENERAL USE  
INSULATED TYPE

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		M	H	
VRRM	Repetitive peak reverse voltage	400	800	V
VRSM	Non-repetitive peak reverse voltage	480	960	V
VR (DC)	DC reverse voltage	320	640	V
VDRM	Repetitive peak off-state voltage	400	800	V
VDSM	Non-repetitive peak off-state voltage	480	960	V
VD (DC)	DC off-state voltage	320	640	V

Symbol	Parameter	Conditions	Ratings	Unit
$I_T$ (RMS), $I_F$ (RMS)	RMS current		205	A
$I_T$ (AV), $I_F$ (AV)	Average current	Single-phase, half-wave 180° conduction, $T_C=85^\circ\text{C}$	130	A
$I_{TSM}$ , $I_{FSM}$	Surge (non-repetitive) current	One half cycle at 60Hz, peak value	2600	A
$I^2t$	$I^2t$ for fusing	Value for one cycle of surge current	$2.8 \times 10^4$	$\text{A}^2\text{s}$
$di/dt$	Critical rate of rise of on-state current	$V_D=1/2V_{DRM}$ , $I_G=1.0\text{A}$ , $T_j=125^\circ\text{C}$	100	$\text{A}/\mu\text{s}$
PGM	Peak gate power dissipation		10	W
PG (AV)	Average gate power dissipation		3.0	W
VFGM	Peak gate forward voltage		10	V
VRGM	Peak gate reverse voltage		5.0	V
IFGM	Peak gate forward current		4.0	A
$T_j$	Junction temperature		-40~125	$^\circ\text{C}$
$T_{stg}$	Storage temperature		-40~125	$^\circ\text{C}$
$V_{iso}$	Isolation voltage	Charged part to case	2500	V
—	Mounting torque	Main terminal screw M8	8.83~10.8	N·m
			90~110	kg·cm
		Mounting screw M6	1.96~3.92	N·m
—	Weight		20~40	kg·cm
		Typical value	300	g

## ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	$T_j=125^\circ\text{C}$ , $V_{RRM}$ applied	—	—	30	mA
IDRM	Repetitive peak off-state current	$T_j=125^\circ\text{C}$ , $V_{DRM}$ applied	—	—	30	mA
$V_{TM}$ , $V_{FM}$	Forward voltage	$T_j=125^\circ\text{C}$ , $I_{TM}=I_{FM}=390\text{A}$ , instantaneous meas.	—	—	1.3	V
$dv/dt$	Critical rate of rise of off-state voltage	$T_j=125^\circ\text{C}$ , $V_D=2/3V_{DRM}$	500	—	—	$\text{V}/\mu\text{s}$
VGT	Gate trigger voltage	$T_j=25^\circ\text{C}$ , $V_D=6\text{V}$ , $R_L=2\Omega$	—	—	3.0	V
VGD	Gate non-trigger voltage	$T_j=125^\circ\text{C}$ , $V_D=1/2V_{DRM}$	0.25	—	—	V
IGT	Gate trigger current	$T_j=25^\circ\text{C}$ , $V_D=6\text{V}$ , $R_L=2\Omega$	15	—	100	mA
$R_{th(j-c)}$	Thermal resistance	Junction to case (per 1/2 module)	—	—	0.22	$^\circ\text{C}/\text{W}$
$R_{th(c-f)}$	Contact thermal resistance	Case to fin, conductive grease applied (per 1/2 module)	—	—	0.1	$^\circ\text{C}/\text{W}$
—	Insulation resistance	Measured with a 500V megohmmeter between main terminal and case	10	—	—	$\text{M}\Omega$

Note: Items of the above table applies to the Thyristor part and the Diode part as circled in the following tables.

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HIGH POWER GENERAL USE  
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## MAXIMUM RATINGS

Item	VRRM	VRSM	VR (DC)	VDRM	VD SM	VD (DC)	IT (RMS)	IT (AV)	ITSM	$i^2t$	di/dt
							IF (RMS)	IF (AV)	IFSM		
Thyristor	○	○	○	○	○	○	○	○	○	○	○
Diode	○	○	○	—	—	—	○	○	○	○	—

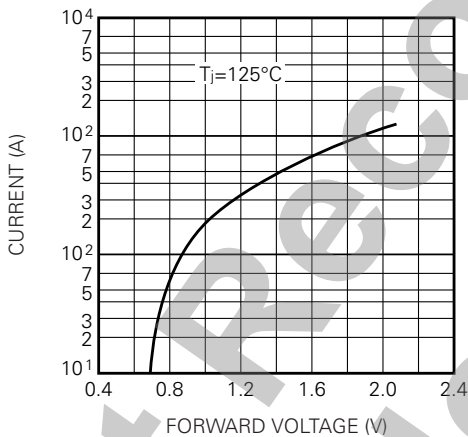
Item	PGM	PG (AV)	VFGM	IFGM	T <sub>j</sub>	T <sub>stg</sub>
Thyristor	○	○	○	○	○	○
Diode	—	—	—	—	○	○

## ELECTRICAL CHARACTERISTICS

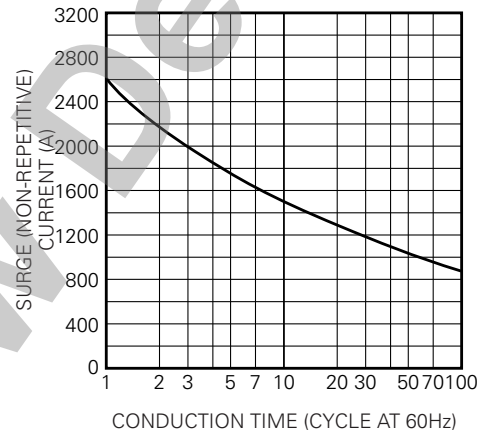
Item	IRRM	IDRM	VTM	dv/dt	VGT	VGD	IGT	R <sub>th(j-c)</sub>	R <sub>th(c-f)</sub>
			VFM						
Thyristor	○	○	○	○	○	○	○	○	○
Diode	○	—	○	—	—	—	—	○	○

## PERFORMANCE CURVES

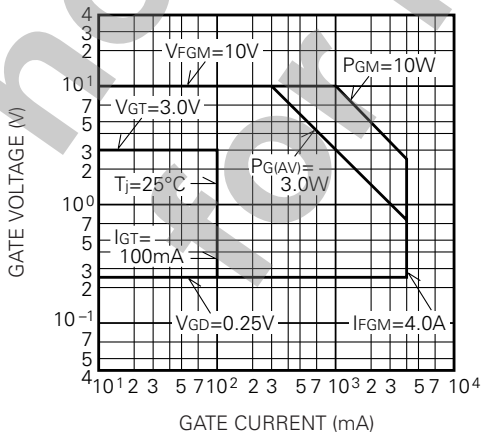
MAXIMUM FORWARD CHARACTERISTIC



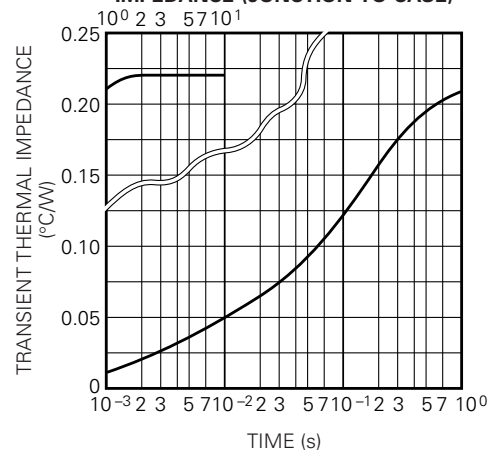
RATED SURGE (NON-REPETITIVE) CURRENT



GATE CHARACTERISTICS



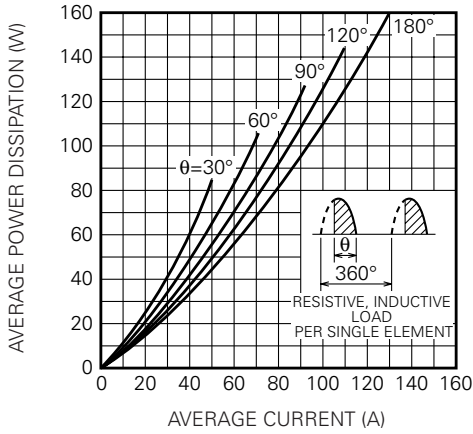
MAXIMUM TRANSIENT THERMAL IMPEDANCE (JUNCTION TO CASE)



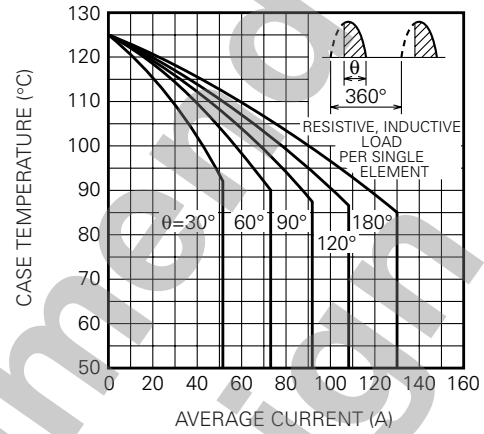
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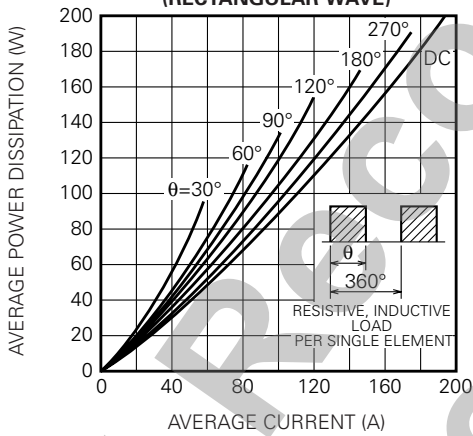
MAXIMUM AVERAGE POWER DISSIPATION (SINGLE PHASE HALF WAVE)



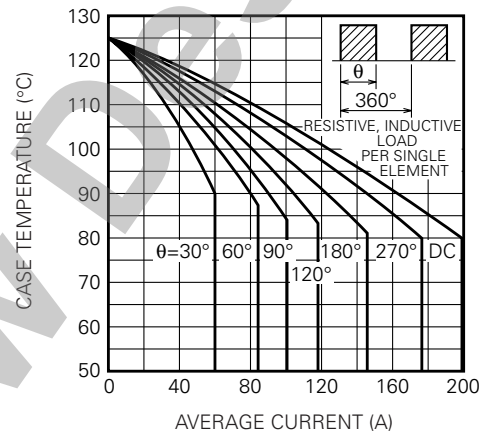
LIMITING VALUE OF THE AVERAGE CURRENT (SINGLE PHASE HALF WAVE)



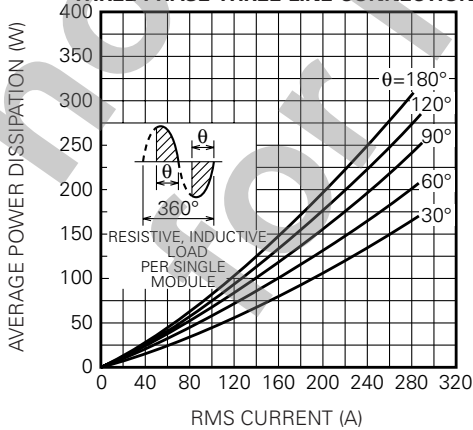
MAXIMUM AVERAGE POWER DISSIPATION (RECTANGULAR WAVE)



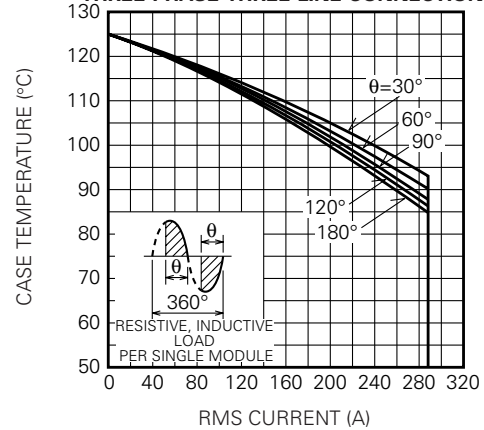
LIMITING VALUE OF THE AVERAGE CURRENT (RECTANGULAR WAVE)



MAXIMUM AVERAGE POWER DISSIPATION (REVERSE-PARALLEL CONNECTION, THREE-PHASE THREE-LINE CONNECTION)



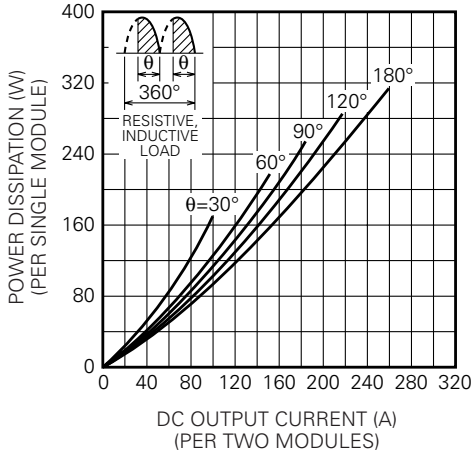
LIMITING VALUE OF THE RMS CURRENT (REVERSE-PARALLEL CONNECTION, THREE-PHASE THREE-LINE CONNECTION)



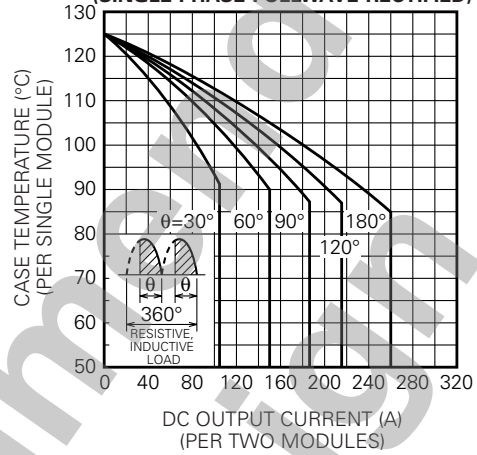
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HIGH POWER GENERAL USE  
INSULATED TYPE

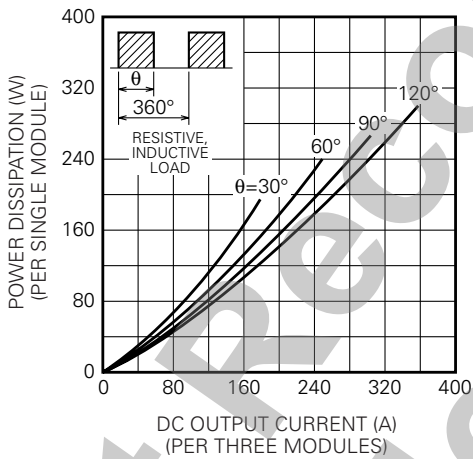
MAXIMUM POWER DISSIPATION  
(SINGLE PHASE FULLWAVE RECTIFIED)



LIMITING VALUE OF THE DC OUTPUT CURRENT  
(SINGLE PHASE FULLWAVE RECTIFIED)



MAXIMUM POWER DISSIPATION  
(THREE-PHASE FULLWAVE RECTIFIED)



LIMITING VALUE OF THE DC OUTPUT CURRENT  
(THREE-PHASE FULLWAVE RECTIFIED)

